

# OSAT Production Testing of 5G, Power Discrete & 3D Packaged ICs

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March 2023



19<sup>TH</sup> INTERNATIONAL CONFERENCE & EXHIBITION ON  
**DEVICE PACKAGING**  
FOUNTAIN HILLS, AZ • [WWW.DEVICEPACKAGING.ORG](http://WWW.DEVICEPACKAGING.ORG) • MARCH 13-16, 2023

# Agenda

1 Test Markets

2 5G

3 Power Discrete

4 3D IC

# Test Markets



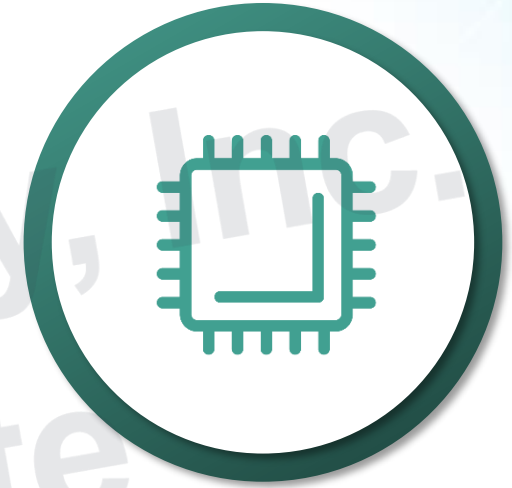
Mobility,  
Communications  
& RF



Automotive



Power  
SiC & GaN



Advanced  
Packages 3D IC

## Test Technologies are Evolving in all Markets

# Agenda

1 Test Markets

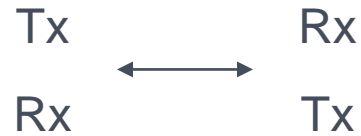
2 5G

3 Power Discrete

4 3D IC

# RF Technology Application Use Cases

## Indoor (Low Power)



1. Wi-Fi, BT, NFC, IoT
2. Carrier frequency
3. Bandwidth
4. Power at FC: Operational range
5. Number of users
6. Interferences

## Outdoor (High Power)



1. Cellphone 3GPP, BS, satellite
2. Carrier frequency
3. Bandwidth
4. Power at FC: Operational range
5. Number of users
6. Interferences

**All RF Technologies, All Package Types, Including AiP**



# 5G Test Transition & Challenge

1G-4G



RF 600 MHz ~6 GHz

- ▶ Filters
- ▶ Switch
- ▶ PA
- ▶ FEM
- ▶ Attenuators



Source: [lora-alliance.org](https://lora-alliance.org)

~800 MHz band



Source: [wi-fi.org](https://wi-fi.org)

2.4 GHz & 5.8 GHz bands  
802.11 A, B, G, N, AC



Source: [ezzigbee.com](https://ezzigbee.com)

2.4 GHz band



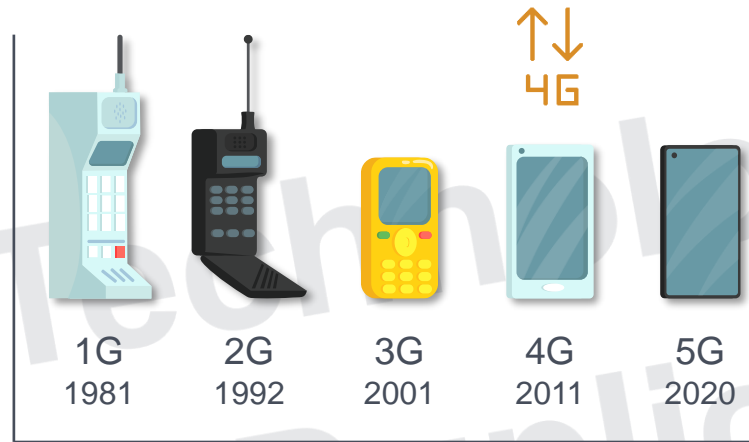
Source: [bluetooth.com](https://bluetooth.com)

2.45 GHz band

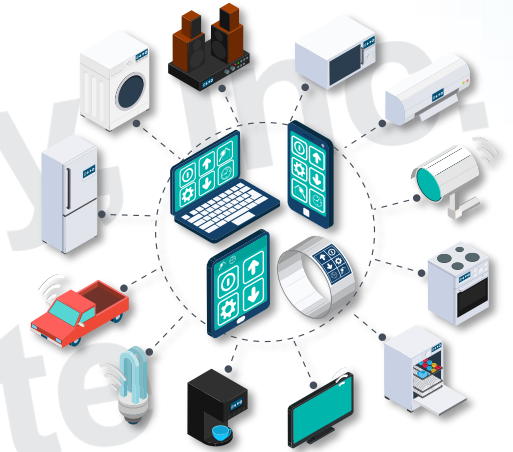


GNSS, GPS  
~1.5 GHz band

Latency &  
Speeds  
(BW)



2.4 GHz & 5.8 GHz bands



Internet of Things

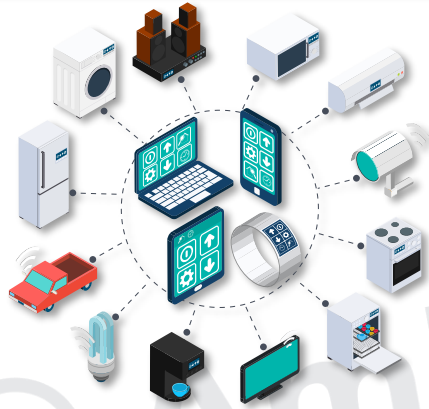
# 5G Test Transition & Challenge

4G

5G

FR1

FR2



**NB Internet of Things**

3GPP – FEM, SW/Trans. PA, LNA, Ant.  
100 MHz – 800 MHz BW



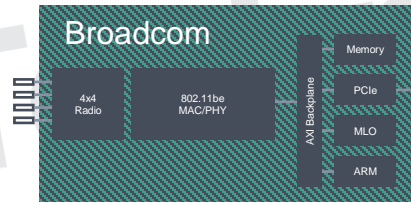
Source: [analog.com](https://www.analog.com)



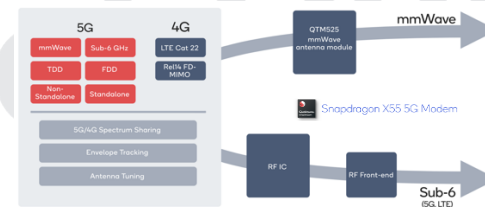
Source: [wikipedia.org](https://en.wikipedia.org/wiki/WiGig)

802.11ad/ay (57-66 GHz),  
~2 GHz BW: Transceivers

**Wi-Fi 6,7**  
802.11ax/be  
1024...4096 QAM  
160-320 MHz BW



Source: [broadcom.com](https://www.broadcom.com)



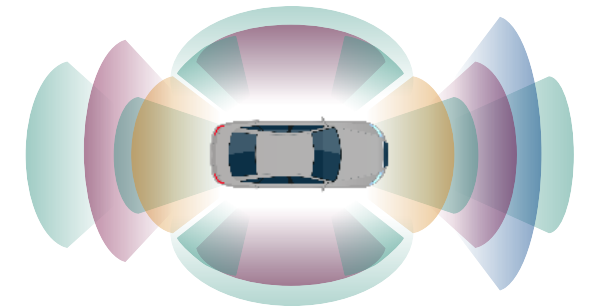
Source: [qualcomm.com](https://www.qualcomm.com)

**Ultra-low Latency, Multi-Gb Throughput,  
High Connection Count**

**Skyworks**  
Sky5

5G NR ultra high band Tx, Rx, MIMO,  
BT, GPS, Wi-Fi, ant: Mux, ant tuning SW,  
PA

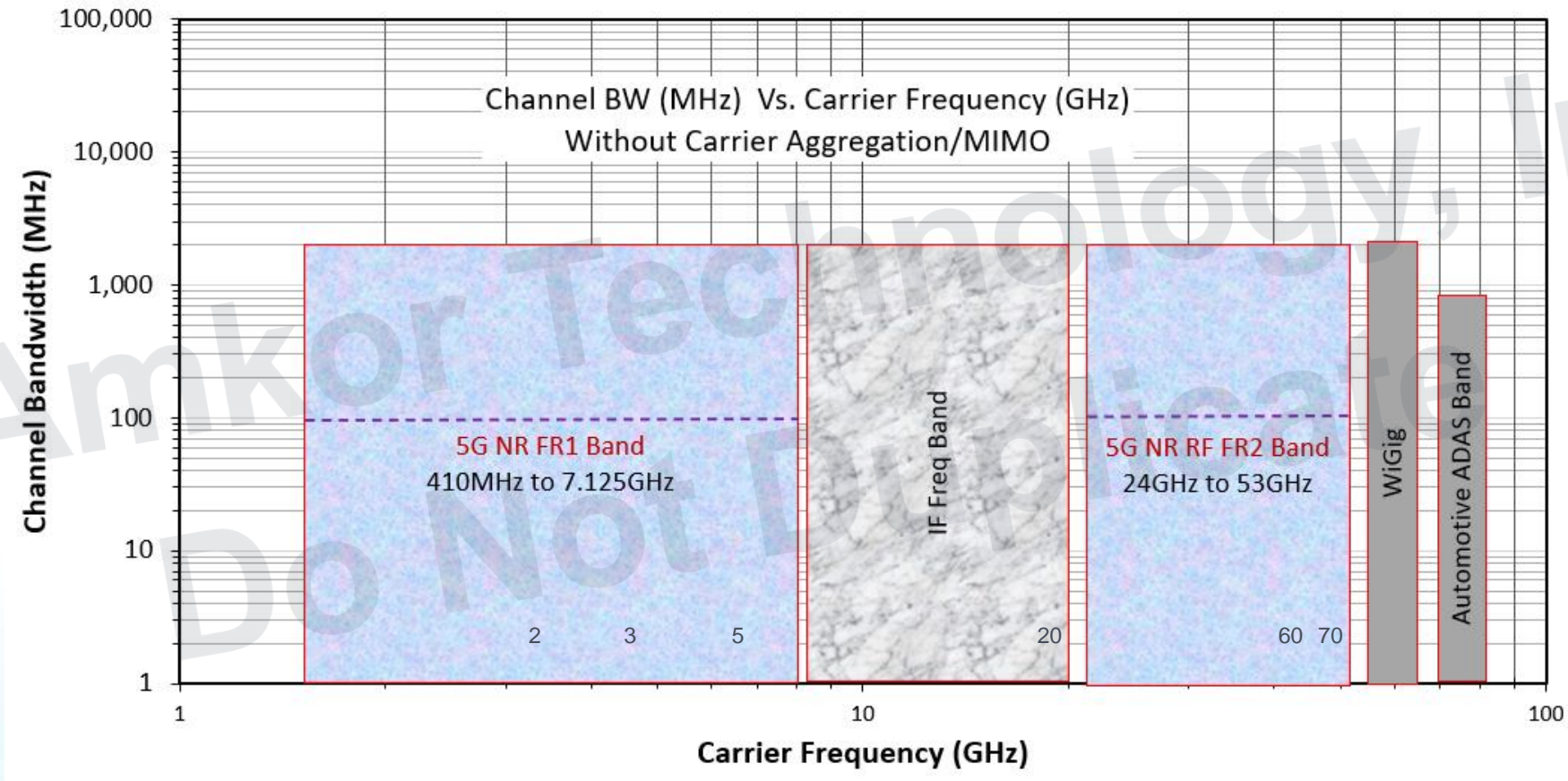
Large product volumes



**Automotive Radar**

Automotive (76-81GHz),  
0.6-4 GHz BW; transceiver

# RF 5G & mmWave Band Segmentation

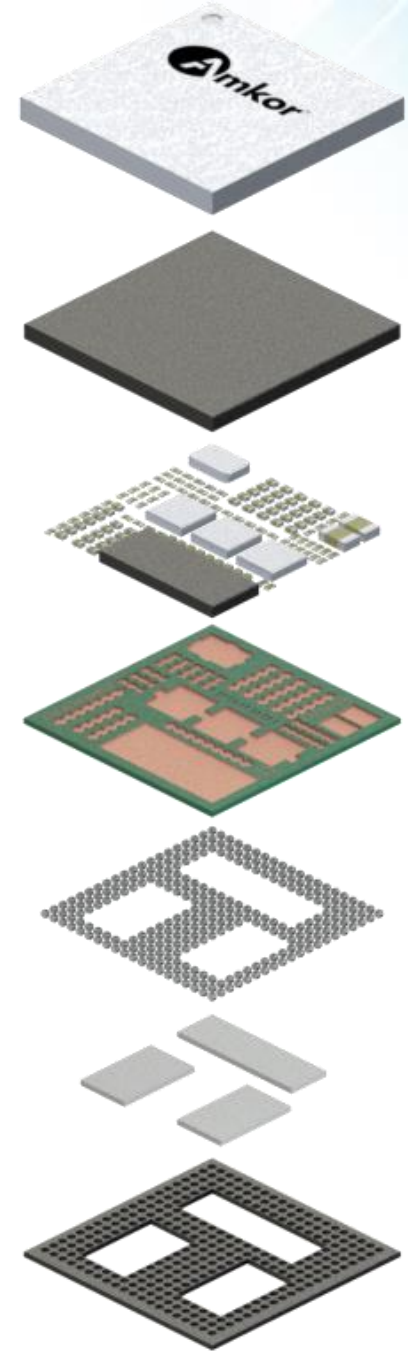


## Amkor RF Products in All Bands!

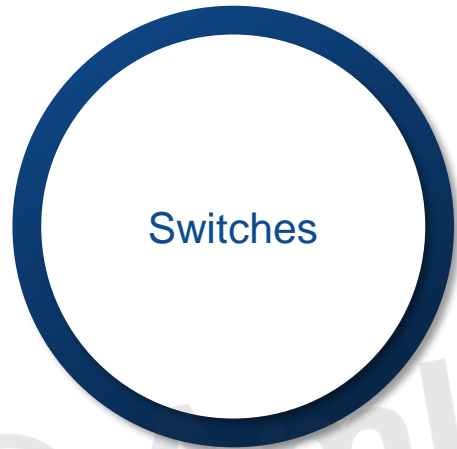


# Amkor's DSMBGA RFFE

- ▶ Double sided component attach
- ▶ Double sided mold
- ▶ Conformal & shielding
- ▶ RFFE: LNA, PA, switch, filters & duplexers
- ▶ Production test



# 5G Broadband Products

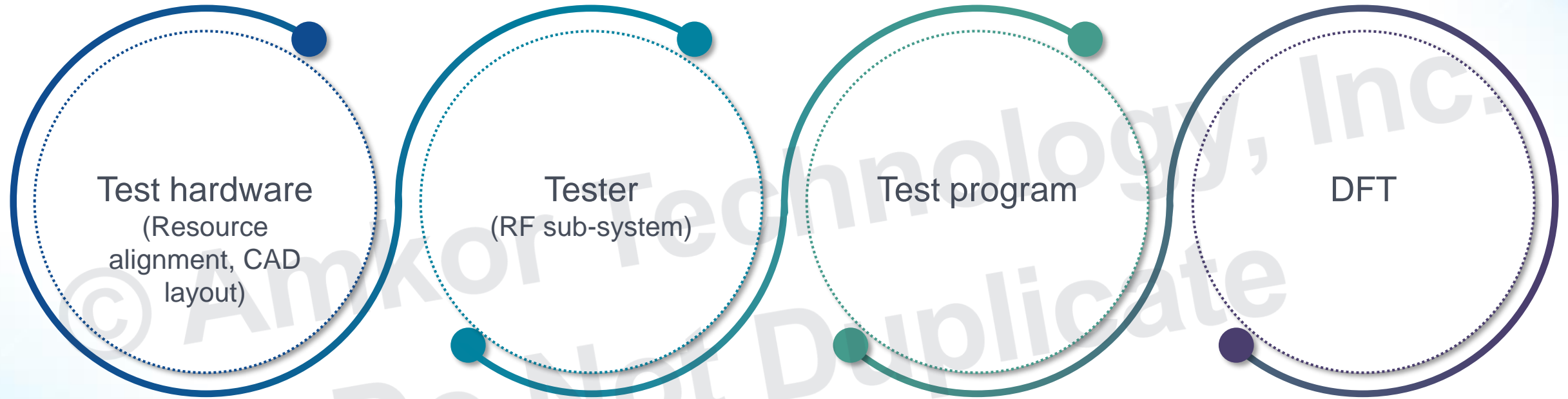


Base Station + User Equipment

WLCSP, LGA, BGA

Antenna Integration

# Production Test Challenges



**5G is Forcing All Aspects of Production Application Design to Evolve**

# Agenda

1 Test Markets

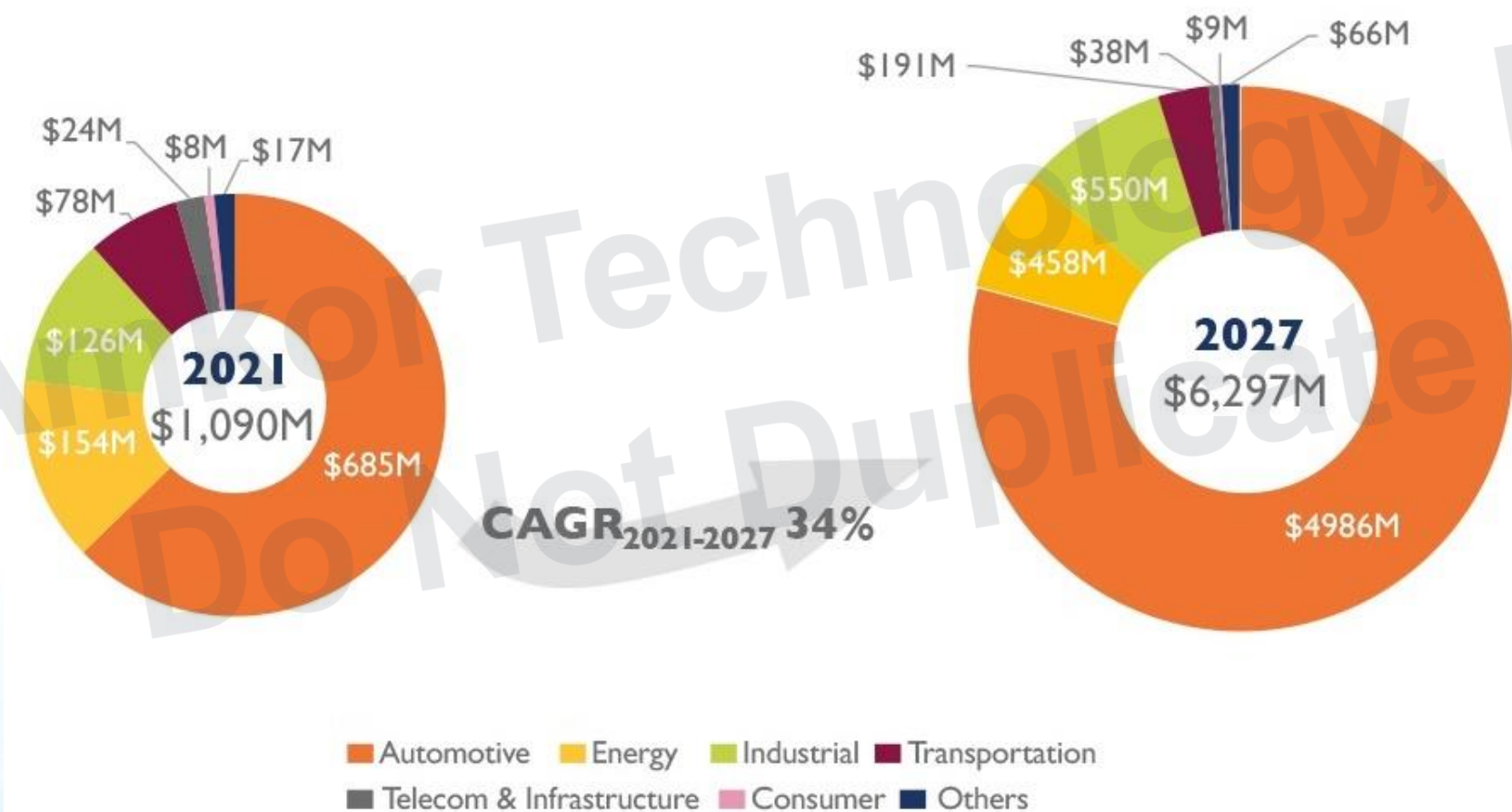
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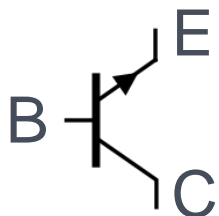
# 2021-2027 Power SiC Devices by Market Segment



Source: Yole Intelligence March 2022

# Power Technology Target Specifications

IGBT, MOSFET – Si, SiC, GaN Single & Modules



Pathfinding/Definition/Development

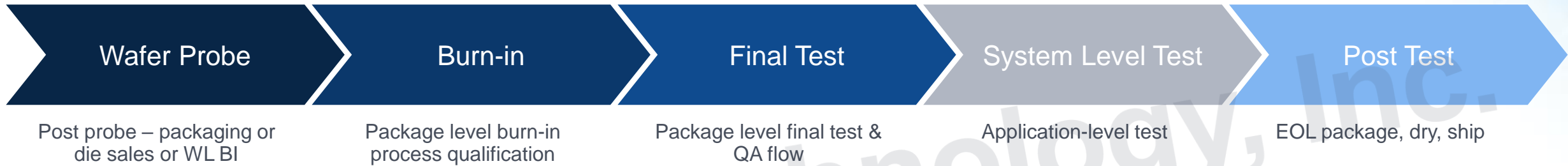
Deployment

Perf Attribution	Si (1.1eV)	GaN (3.4eV)	SiC (3.2eV)
DC $V_{CE}$ , $V_{BE}$ , $I_D$ , Gain, $R_{DS-On}$ Temp	~100V, nom power density, efficiency	~150V, med-power density, efficiency	~1800V, high power density; high efficiency
AC Frequency, $I_{Pulse}$ , $C_g$ , $T_{On}$ , $T_{Off}$ , UIS, $T_{rr}$	Nom SW frequency	Hi SW frequency	Med-high SW frequency

Higher Power, Higher Thermal Considerations During Product Test

# Power Technology Target Specifications

## Test Flow



- ▶ In production (today)
  - ▷ Final test & post test
  - ▷ Max envelope: 900V/10A-75V/160A
- ▶ Explore
  - ▷ Probe, burn-in, system level test
  - ▷ Wider discrete, modules
  - ▷ Max envelope: >2000V/700A

# Test Equipment Suppliers

Teradyne	UNITES	PowerTECH	SPEA
Tesec	AccoTEST	Microtest	Focused Test
ADVANTEST	LEMSYS	Shibasoku	CREA

**Tester, Package Handler and Burn-in Platforms are Being Deployed**



# Agenda

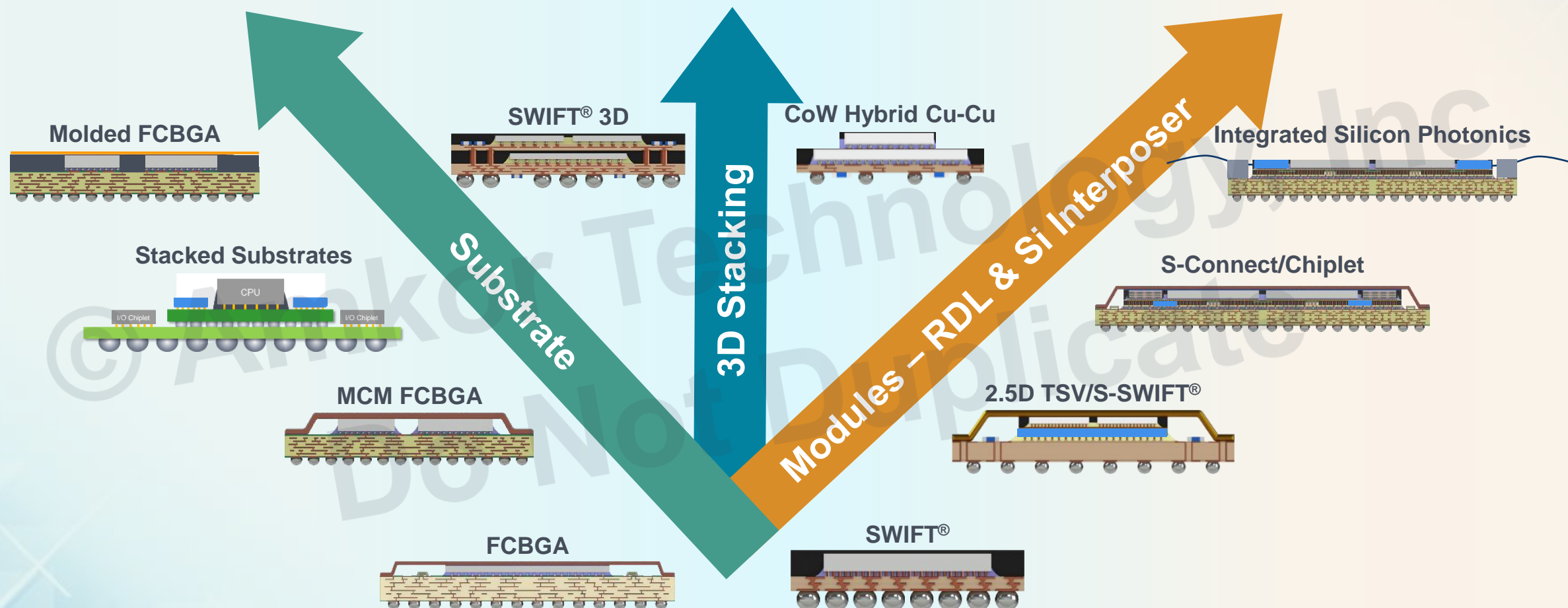
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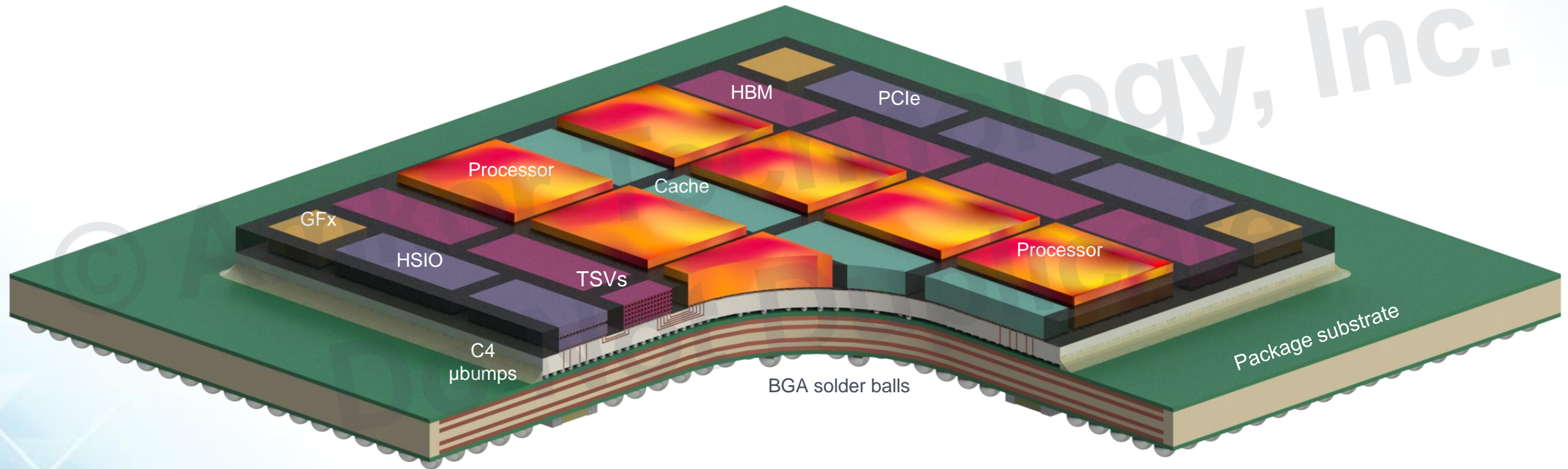
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# Amkor Multi-Die Package Technologies

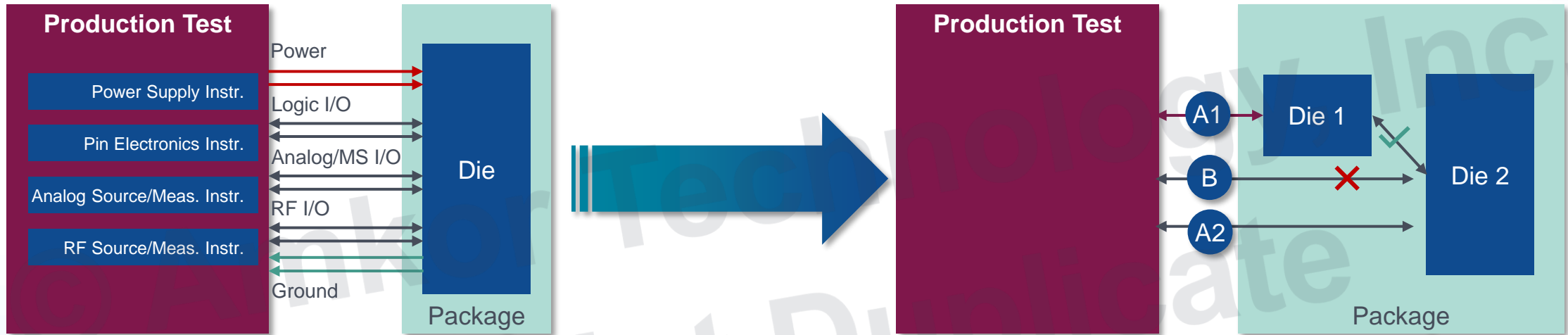


**Die Disaggregation to Allow Higher Levels of Integration!**

# Amkor Package Assembly Topologies



# Production Test Challenges



- ▶ No direct access
- ▶ Radiative access
- ▶ Digital system bus protocol

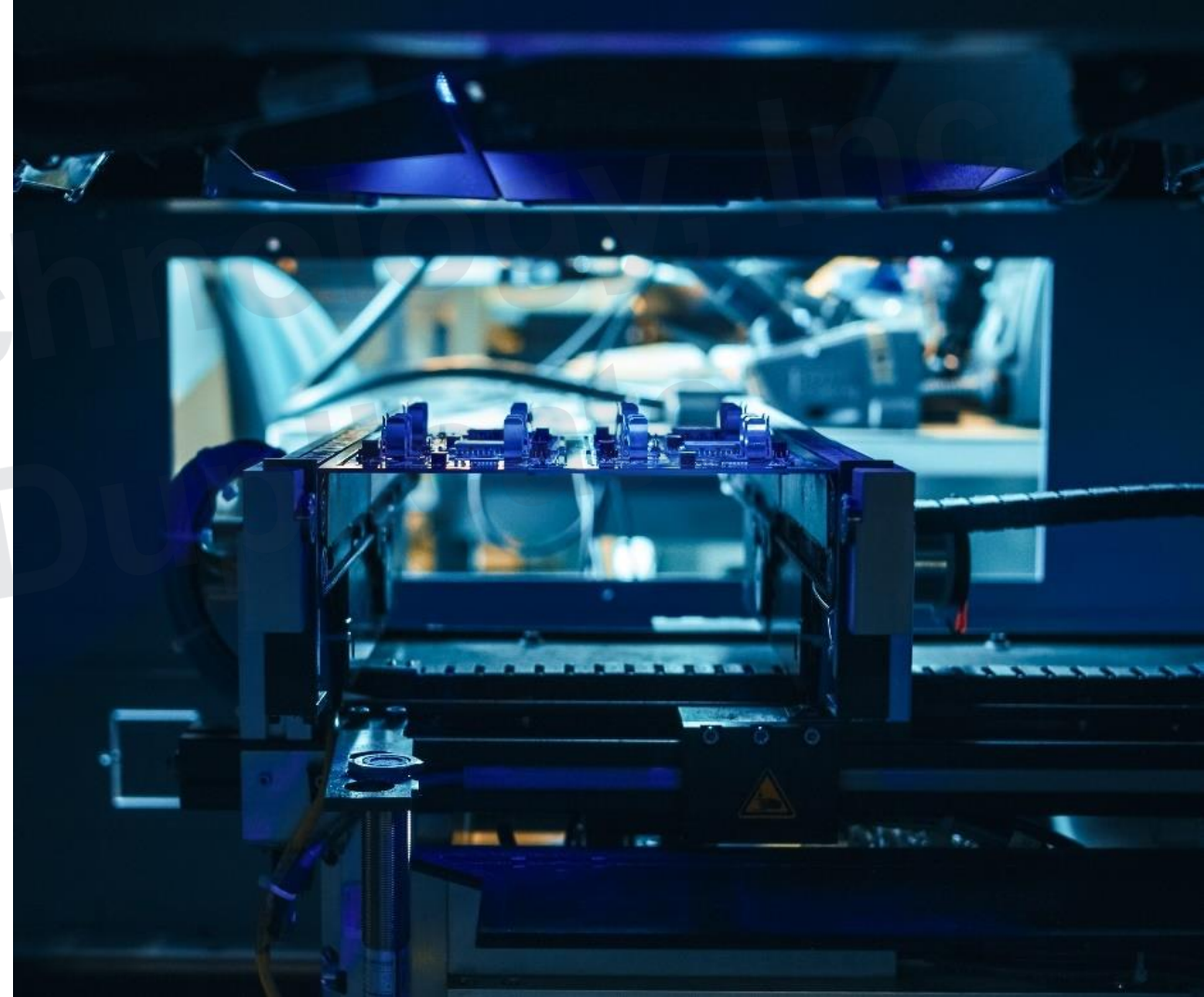
Die 2 interface physically

- A Pinned out
- B Not pinned out



# Production Test Methodology – DFT

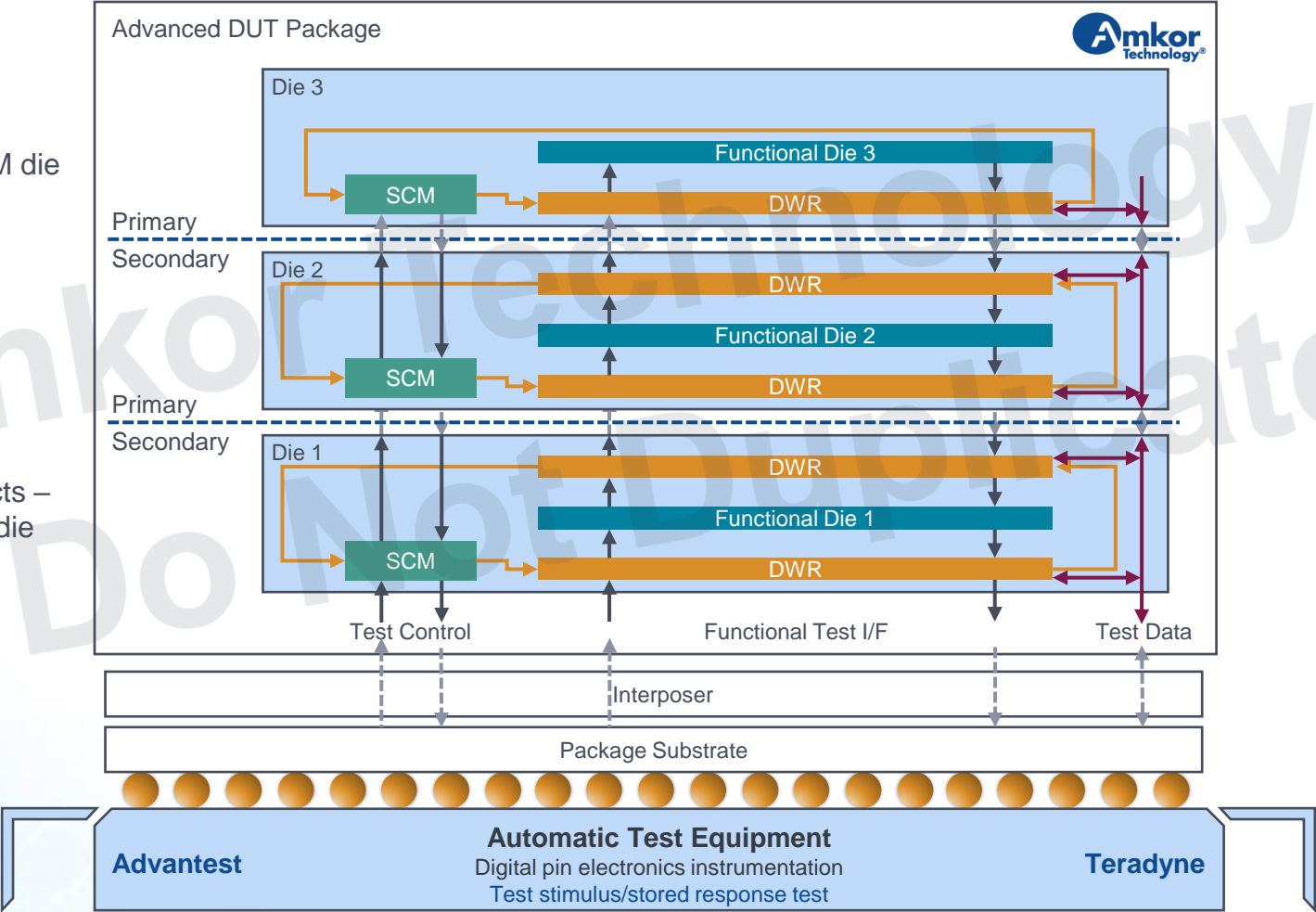
- ▶ Functional & structural test content
  - ▷ BIST, SBFT, scan – IEEE 1149.x, 1500, 1687, 1838
- ▶ Digital test instrumentation features
- ▶ Concurrent testing



# 3D IC Test View

CPU (logic), GPU, DDR/HBM die

**Test challenge:** Interconnects – substrate, interposer, die-to-die

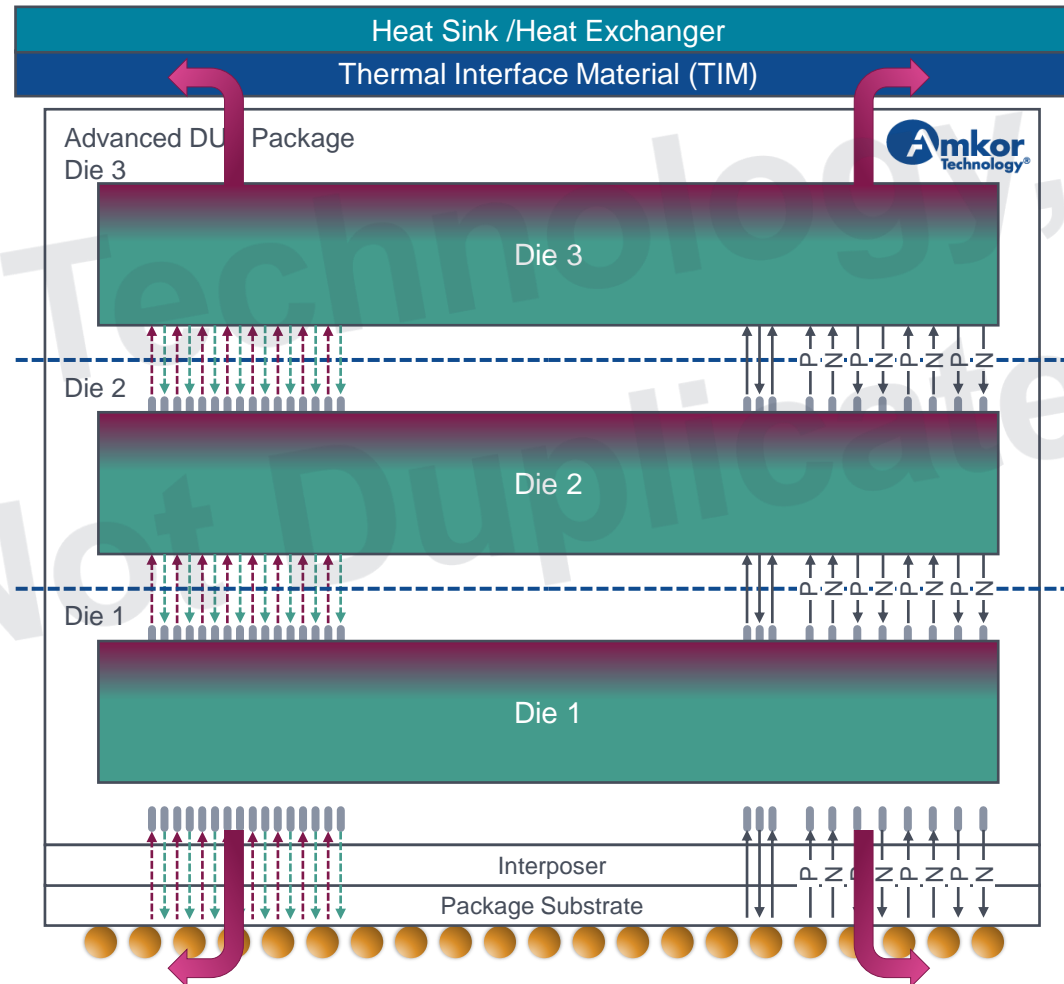


DWR: Die Wrapper Register  
SCM: Serial Control Mechanism  
FPP: Flexible Parallel Port

Source: IEEE1838-2019

# 3D IC Test Challenge

- ▶ Power
  - ▷ Cu pillar &  $\mu$ bump – contact resistance
- ▶ Signal
  - ▷ Capacitive loading for signal & ground
  - ▷ Crosstalk & increased noise in Si substrate
  - ▷ Insertion loss & return loss – via/bump interface
- ▶ Thermal
  - ▷ Interconnect/underfill layers
  - ▷ End-of-the-line layers
  - ▷ Bulk silicon
  - ▷  $\mu$ bump
  - ▷ Heat sink



## Call for Action

- ▶ Production test simplification
- ▶ Standardization
- ▶ Enable re-use

# Production Test – Impact to Test Flow

Single chip production test flow



**Alter Test Flow**

**Test Content Re-distribution**

**Platform Level Test Quality**



# Summary

- ▶ Multi-die packages allow for denser integration
- ▶ Business continues to have economic and performance challenges
- ▶ Call to action – advanced test methods
- ▶ Amkor is the industry leader in advanced packaging and production test solutions



# Amkor Test Services



**24/7**

Operation of fully networked test floors



## Test Development

Software & hardware for probe, strip, final and system level test

**>3,600 Testers  
in 7 Locations**

3,000 + Amkor, 600 + consigned



## Accurate and Thorough Test Services

Wafer probe, final test, strip test, film frame test, system level test, opens/shorts test, burn-in and complete end-of-line



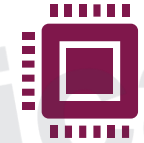
## Full End-of-Line Processing

Bake, scan, pack, ship and finished good services



## Testing for Commercial, Industrial & Automotive Devices

Discrete, power, mixed-signal, memory, RF, MEMS and SiP devices



**Tested Annually**  
10 Billion units  
7-9 Million wafers

Test is an integral part of the overall Amkor business  
Over 40 years of Automotive test experience

[amkor.com/test-services](https://amkor.com/test-services)





# Thank You

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Learn more ► [amkor.com/test-services/](https://amkor.com/test-services/)



# Abstract: OSAT Production Testing of 5G, Power Discretes & 3D Packaged ICs

- ▶ The presentation will be segmented into three. OSAT production testing challenges of three vital product families that are important to our semiconductor industry will be showcased in each segment. The first segment will describe the products and impacts to RF production testing of both Sub-8GHz carrier frequency range and the mmWave frequency range of operation. The second segment will explore emerging MOSFET technologies that enable faster switching rates and higher voltage and current topologies. The third segment will describe the challenges of production test content for 3D-stacked advanced packages.
- ▶ 5G RF has enabled mmWave carrier frequencies, small cell deployment, massive MIMO (Multiple In, Multiple Out), beam forming, and full duplex wireless transmission and reception operations. These features require new production test methodologies.
- ▶ There is an astronomical rise in battery powered applications like toys, consumer goods, automotive and trains. Power path turn on/off with MOSFETs is in the critical path. The technology has advanced from the traditional Si to GaN and SiC based products that have a smaller size and allow for higher application efficiencies. Test specifications and limits are improving and production testing methods are evolving to account for these changes.
- ▶ Advanced packaging has enabled the path to integrate chiplets within a single package. Heterogeneous Integration (HI) is a powerful design innovation that allows tighter integration and, in some cases, improved signal and power performance at the system level. Production test methodologies are being streamlined to make test a competitive advantage for our customers.